

# UMS-1200-A16-G

### OCTAVE BAND VOLTAGE CONTROLLED OSCILLATOR

Package: A16, 12.7mm x 12.7mm x 3.43mm

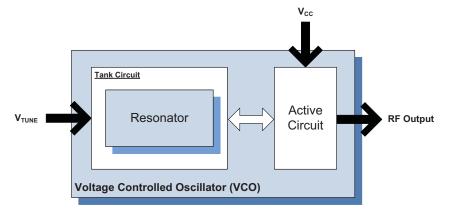


## Features

- Octave Band Tuning
- Frequency: 600MHz to 1200MHz
- Resonator: Microstrip
- PCB: Rogers
- Package Size: 12.7mm x 12.7mm x 3.43mm (0.5in x 0.5in x 0.135in)

# Applications

- Wide Band Applications
- Built-in Test Applications
- First LO Applications
- Frequency Sythesizers



Functional Block Diagram

## **Product Description**

This series of VCO modules features full octave bands (typical), low phase noise, low harmonics, and linear tuning.

### **Ordering Information**

UMS-1200-A16-G Contact us at 1-480-756-6070

### **Optimum Technology Matching® Applied**

GaAs HBT GaAs MESFET InGaP HBT

support, contact

SiGe BiCMOS
Si BiCMOS
SiGe HBT

332-678-5570 or customerspryice@rfmd.

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#### **Absolute Maximum Ratings**

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Parameter	Rating	Unit
Operating Ambient Temperature[1]	-40 to +85	°C
Storage Temperature	-55 to +125	°C

[1] Frequency drift: 15.0MHz typical, 25.0MHz maximum (either extreme)



#### Caution! ESD sensitive device.

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

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RoHS (Restriction of Hazardous Substances): Compliant per EU Directive 2002/95/EC.

Parameter		Specification		Linit —	<b>O</b> oundition
	Min.	Тур.	Max.	Unit	Condition
Overall					
Frequency Range	600		1200	MHz	
Tuning Voltage	0.5		12	V <sub>DC</sub>	
Tuning Sensitivity	40	60	95	MHz/V	
Output Power	9.5	12	13.5	dBm	
	9			dBm	At V <sub>T</sub> =0
Output Phase Noise		-82	-75	dBc/Hz	1kHz
		-104	-99	dBc/Hz	10kHz
		-124	-119	dBc/Hz	100 kHz
		-144	-139	dBc/Hz	1000 kHz
		-164	-155	dBc/Hz	10000kHz
Second Harmonic		-20	-10	dBc	
Frequency Pulling		5	15	MHz p-p	At 12dBr, all phases
Tuning Port Capacitance		100		pF	
Modulation Bandwidth		10000		kHz	3dB BW
Frequency Pushing		0.2	1	MHz/V	
Power Supply					
Operating Voltage		12		V	
Supply Current		29		mA	





# Package Drawing & Pin Outs

12.7mm x 12.7mm x 3.43mm (0.5in x 0.5in x 0.135in)

